# PH1214-110M

# Radar Pulsed Power Transistor 110W, 1.2-1.4 GHz, 150µs Pulse, 10% Duty

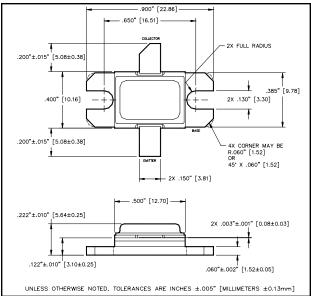
#### Features

- NPN silicon microwave power transistors
- Common base configuration
- Broadband Class C operation
- High efficiency inter-digitized geometry
- Diffused emitter ballasting resistors
- Gold metallization system
- · Internal input and output impedance matching
- Hermetic metal/ceramic package
- RoHS compliant



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#### **Outline Drawing**



#### Absolute Maximum Ratings at 25°C

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	V <sub>CES</sub>	70	V
Emitter-Base Voltage	V <sub>EBO</sub>	3.0	V
Collector Current (Peak)	Ι <sub>C</sub>	10.5	А
Power Dissipation @ +25°C	P <sub>TOT</sub>	350	W
Storage Temperature	T <sub>STG</sub>	-65 to +200	°C
Junction Temperature	TJ	200	°C

#### Electrical Specifications: T<sub>c</sub> = 25 ± 5°C (Room Ambient )

Parameter	Test Conditions	Frequency	Symbol	Min	Мах	Units
Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 100mA		BV <sub>CES</sub>	70	-	V
Collector-Emitter Leakage Current	V <sub>CE</sub> = 40V		I <sub>CES</sub>	-	5.5	mA
Thermal Resistance	Vcc = 40V, Pin = 20W	F = 1.2, 1.3, 1.4 GHz	R <sub>TH(JC)</sub>	-	0.5	°C/W
Output Power	Vcc = 40V, Pin = 20W	F = 1.2, 1.3, 1.4 GHz	P <sub>OUT</sub>	110	-	W
Power Gain	Vcc = 40V, Pin = 20W	F = 1.2, 1.3, 1.4 GHz	G <sub>P</sub>	7.4	-	dB
Collector Efficiency	Vcc = 40V, Pin = 20W	F = 1.2, 1.3, 1.4 GHz	η <sub>c</sub>	50	-	%
Input Return Loss	Vcc = 40V, Pin = 20W	F = 1.2, 1.3, 1.4 GHz	RL	-	-9	dB
Load Mismatch Tolerance	Vcc = 40V, Pin = 20W	F = 1.2, 1.3, 1.4 GHz	VSWR-T	-	3:1	-
Load Mismatch Stability	Vcc = 40V, Pin = 20W	F = 1.2, 1.3, 1.4 GHz	VSWR-S	-	1.5:1	-

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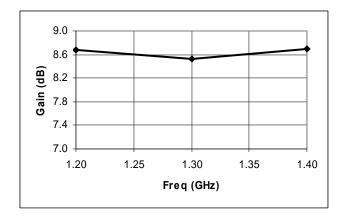
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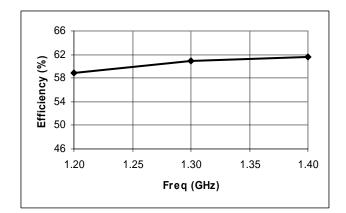
#### **Typical RF Performance**

Freq. (GHz)	Pin (W)	Pout (W)	Gain (dB)	lc (A)	Eff (%)	RL (dB)	VSWR-S (1.5:1)	VSWR-T (3:1)
1.2	20	148	8.68	6.26	59.0	-10.0	S	Р
1.3	20	143	8.53	5.86	60.8	-11.0	S	Р
1.4	20	148	8.69	6.00	61.7	-25.6	S	Р

Gain vs. Frequency



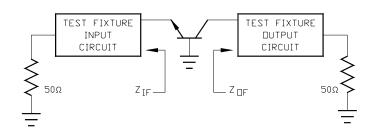
## **Collector Efficiency vs. Frequency**



#### **RF Test Fixture Impedance**

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F (GHz)	Z <sub>IF</sub> (Ω)	Z <sub>OF</sub> (Ω)		
1.2	4.7 - j4.4	4.4 - j3.3		
1.3	4.5 - j3.3	3.0 - j2.8		
1.4	4.5 - j2.3	2.3 - j1.8		



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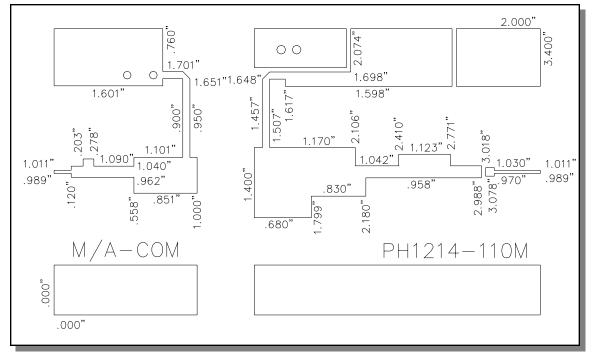
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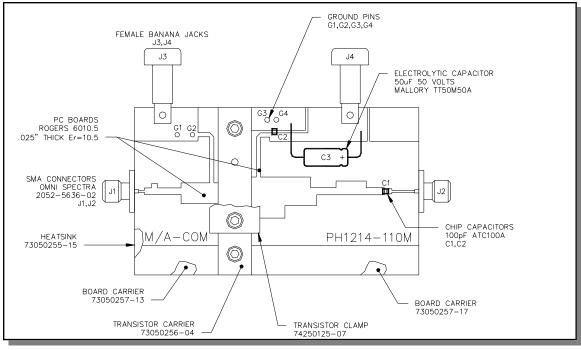
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## **Test Fixture Circuit Dimensions**



# **Test Fixture Assembly**

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